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L5 and (resist near5 patterning)

3

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<u>L6</u>	L5 and (resist near5 patterning)	3	<u>L6</u>
<u>L5</u>	L4 and (copper near2 plating)	65	<u>L5</u>
<u>L4</u>	L1 and cmp	202	<u>L4</u>
<u>L3</u>	L1 and (cmp or (chemical mechanical polishing))	459	<u>L3</u>
<u>L2</u>	L1 and cmp or (chemical mechanical polishing)	1079242	<u>L2</u>
<u>L1</u>	copper adj seed	500	<u>L1</u>

END OF SEARCH HISTORY

**WEST**[Generate Collection](#)[Print](#)**Search Results - Record(s) 1 through 3 of 3 returned.** **1. Document ID: US 6350688 B1**

L6: Entry 1 of 3

File: USPT

Feb 26, 2002

US-PAT-NO: 6350688

DOCUMENT-IDENTIFIER: US 6350688 B1

TITLE: Via RC improvement for copper damascene and beyond  
technology

Full	Title	Citation	Front	Review	Classification	Date	Reference	Sequences	Attachments	Claims	KM/C
Draw Desc	<a href="#">Image</a>										

 **2. Document ID: US 6225226 B1**

L6: Entry 2 of 3

File: USPT

May 1, 2001

US-PAT-NO: 6225226

DOCUMENT-IDENTIFIER: US 6225226 B1

TITLE: Method for processing and integrating copper interconnects

Full	Title	Citation	Front	Review	Classification	Date	Reference	Sequences	Attachments	Claims	KM/C
Draw Desc	<a href="#">Image</a>										

 **3. Document ID: US 6184138 B1**

L6: Entry 3 of 3

File: USPT

Feb 6, 2001

US-PAT-NO: 6184138

DOCUMENT-IDENTIFIER: US 6184138 B1

TITLE: Method to create a controllable and reproducible dual copper  
damascene structure

Full	Title	Citation	Front	Review	Classification	Date	Reference	Sequences	Attachments	KM/C
Draw Desc	<a href="#">Image</a>									

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L5 and (resist near5 patterning)	3

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L10 and (diffusion near barrier)

3

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result set

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<u>L10</u>	L9 and patterning	7	<u>L10</u>
<u>L9</u>	L8 and plating	9	<u>L9</u>
<u>L8</u>	L4 and (developing near5 ( resist or photoresist))	13	<u>L8</u>
<u>L7</u>	L4 and (trimming near5 resist)	0	<u>L7</u>
<u>L6</u>	L5 and (resist near5 patterning)	3	<u>L6</u>
<u>L5</u>	L4 and (copper near2 plating)	65	<u>L5</u>
<u>L4</u>	L1 and cmp	202	<u>L4</u>
<u>L3</u>	L1 and (cmp or (chemical mechanical polishing))	459	<u>L3</u>
<u>L2</u>	L1 and cmp or (chemical mechanical polishing)	1079242	<u>L2</u>
<u>L1</u>	copper adj seed	500	<u>L1</u>

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**WEST**[Generate Collection](#)[Print](#)**Search Results - Record(s) 1 through 7 of 7 returned.** **1. Document ID: US 6433432 B1**

L10: Entry 1 of 7      File: USPT      Aug 13, 2002

US-PAT-NO: 6433432

DOCUMENT-IDENTIFIER: US 6433432 B1

TITLE: Semiconductor device having fluorined insulating film and reduced fluorine at interconnection interfaces and method of manufacturing the same

[Full](#) [Title](#) [Citation](#) [Front](#) [Review](#) [Classification](#) [Date](#) [Reference](#) [Sequences](#) [Attachments](#) [KMC](#)  
[Draw Desc](#) [Image](#) **2. Document ID: US 6420261 B2**

L10: Entry 2 of 7      File: USPT      Jul 16, 2002

US-PAT-NO: 6420261

DOCUMENT-IDENTIFIER: US 6420261 B2

TITLE: Semiconductor device manufacturing method

[Full](#) [Title](#) [Citation](#) [Front](#) [Review](#) [Classification](#) [Date](#) [Reference](#) [Sequences](#) [Attachments](#) [KMC](#)  
[Draw Desc](#) [Image](#) **3. Document ID: US 6280640 B1**

L10: Entry 3 of 7      File: USPT      Aug 28, 2001

US-PAT-NO: 6280640

DOCUMENT-IDENTIFIER: US 6280640 B1

TITLE: Process for manufacturing a chip carrier substrate

[Full](#) [Title](#) [Citation](#) [Front](#) [Review](#) [Classification](#) [Date](#) [Reference](#) [Sequences](#) [Attachments](#) [KMC](#)  
[Draw Desc](#) [Image](#) **4. Document ID: US 6262376 B1**

L10: Entry 4 of 7      File: USPT      Jul 17, 2001

US-PAT-NO: 6262376  
DOCUMENT-IDENTIFIER: US 6262376 B1

TITLE: Chip carrier substrate

Full	Title	Citation	Front	Review	Classification	Date	Reference	Sequences	Attachments
<a href="#">Draw Desc</a>   <a href="#">Image</a>									KMC

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5. Document ID: US 6110819 A

L10: Entry 5 of 7                  File: USPT                  Aug 29, 2000

US-PAT-NO: 6110819  
DOCUMENT-IDENTIFIER: US 6110819 A

TITLE: Interconnect structure using Al.sub.2 Cu for an integrated circuit chip

Full	Title	Citation	Front	Review	Classification	Date	Reference	Sequences	Attachments
<a href="#">Draw Desc</a>   <a href="#">Image</a>									KMC

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6. Document ID: US 5925933 A

L10: Entry 6 of 7                  File: USPT                  Jul 20, 1999

US-PAT-NO: 5925933  
DOCUMENT-IDENTIFIER: US 5925933 A

TITLE: Interconnect structure using Al.sub.2 -Cu for an integrated circuit chip

Full	Title	Citation	Front	Review	Classification	Date	Reference	Sequences	Attachments
<a href="#">Draw Desc</a>   <a href="#">Image</a>									KMC

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7. Document ID: US 5565707 A

L10: Entry 7 of 7                  File: USPT                  Oct 15, 1996

US-PAT-NO: 5565707  
DOCUMENT-IDENTIFIER: US 5565707 A

TITLE: Interconnect structure using a Al.sub.2 Cu for an integrated circuit chip

Full	Title	Citation	Front	Review	Classification	Date	Reference	Sequences	Attachments
<a href="#">Draw Desc</a>   <a href="#">Image</a>									KMC

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L9 and patterning	7

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L11: Entry 1 of 3

File: USPT

Aug 29, 2000

US-PAT-NO: 6110819

DOCUMENT-IDENTIFIER: US 6110819 A

TITLE: Interconnect structure using Al.sub.2 Cu for an integrated circuit chip

<a href="#">Full</a>	<a href="#">Title</a>	<a href="#">Citation</a>	<a href="#">Front</a>	<a href="#">Review</a>	<a href="#">Classification</a>	<a href="#">Date</a>	<a href="#">Reference</a>	<a href="#">Sequences</a>	<a href="#">Attachments</a>	<a href="#">KMC</a>
<a href="#">Draw Desc</a>	<a href="#">Image</a>									

 **2. Document ID: US 5925933 A**

L11: Entry 2 of 3

File: USPT

Jul 20, 1999

US-PAT-NO: 5925933

DOCUMENT-IDENTIFIER: US 5925933 A

TITLE: Interconnect structure using Al.sub.2 -Cu for an integrated circuit chip

<a href="#">Full</a>	<a href="#">Title</a>	<a href="#">Citation</a>	<a href="#">Front</a>	<a href="#">Review</a>	<a href="#">Classification</a>	<a href="#">Date</a>	<a href="#">Reference</a>	<a href="#">Sequences</a>	<a href="#">Attachments</a>	<a href="#">KMC</a>
<a href="#">Draw Desc</a>	<a href="#">Image</a>									

 **3. Document ID: US 5565707 A**

L11: Entry 3 of 3

File: USPT

Oct 15, 1996

US-PAT-NO: 5565707

DOCUMENT-IDENTIFIER: US 5565707 A

TITLE: Interconnect structure using a Al.sub.2 Cu for an integrated circuit chip

<a href="#">Full</a>	<a href="#">Title</a>	<a href="#">Citation</a>	<a href="#">Front</a>	<a href="#">Review</a>	<a href="#">Classification</a>	<a href="#">Date</a>	<a href="#">Reference</a>	<a href="#">Sequences</a>	<a href="#">Attachments</a>	<a href="#">KMC</a>
<a href="#">Draw Desc</a>	<a href="#">Image</a>									

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